





400V PNP HIGH-VOLTAGE TRANSISTOR IN E-LINE

Features

- BVcEo > -400V
- Ic = -200mA Continuous Current
- P_D = 1W Power Dissipation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The ZTX558Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

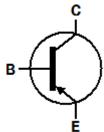
Mechanical Data

- Package: E-Line
- Package Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 [®]
- Weight: 159mg (Approximate)

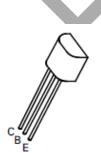








Device Symbol



Top View Pinout

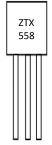
Ordering Information (Note 4)

Orderable Part Number	Package Marking Leads		Loodo	Packing	
Orderable Part Number	Package	Walking	Leads	Qty.	Carrier
ZTX558Q	E-Line	ZTX558	Straight	4,000	Loose in a Box
ZTX558QSTZ	E-Line	ZTX558	Joggled	2,000	Taped per Ammo Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



ZTX 558 = Product Type Marking Code

ZTX558Q Document number: DS33275 Rev. 1 - 4 1 of 7 www.diodes.com



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	-400	V
Collector-Emitter Voltage	VCEO	-400	V
Emitter-Base Voltage	VEBO	-5	V
Collector Current	Ic	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1.5	W
Power Dissipation (Note 6)	PD	1	W
Thermal Resistance Junction to Ambient (Note 5)	R _{0JA}	116	°C/W
Thermal Resistance Junction to Ambient (Note 6)	Reja	175	°C/W
Thermal Resistance Junction to Lead (Note 7)	Rejl	63.75	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +200	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- For a through-hole device mounted at the seating plane (2.5mm lead length) with the collector lead on 25mm × 25mm 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady state.
 Same as Note 5, except the device is mounted on minimum recommended pad layout with 12mm lead length from the bottom of package to the board.
 Thermal resistance from junction to solder-point at the seating plane (2.5mm from the bottom of package along the collector lead).
 Refer to JEDEC specifications JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating Information

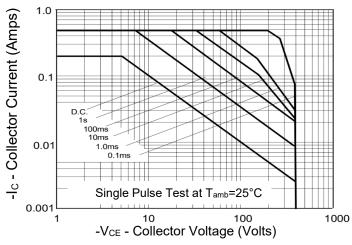


Figure 1. Safe Operating Area

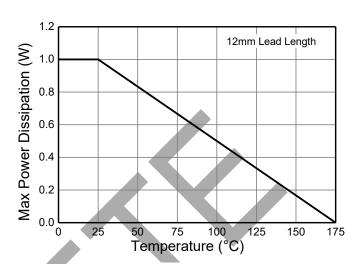


Figure 2. Derating Curve

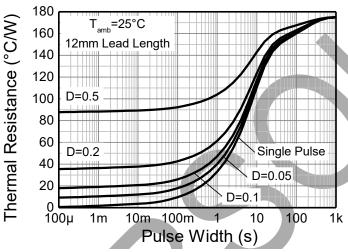


Figure 3. Transient Thermal Impedance

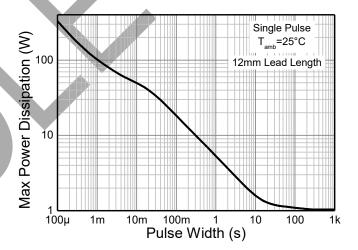


Figure 4. Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

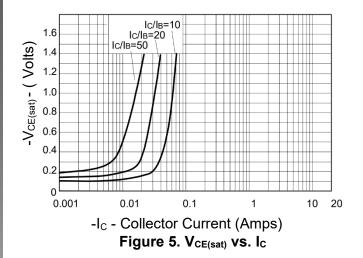
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-400	_	_	V	Ic = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BVceo	-400	_	_	V	Ic = -10mA
Emitter-Base Breakdown Voltage	BVEBO	-5	_		V	I _E = -100μA
DC Current Gain (Note 9)	hFE	100 100 15	_ _ _	300 —	_ _ _	V _{CE} = -10V, I _C = -1mA V _{CE} = -10V, I _C = -50mA V _{CE} = -10V, I _C = -100mA
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)	_	_	-0.2 -0.5	V V	Ic = -20mA, I _B = -2mA Ic = -50mA, I _B = -6mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	_	-0.9	V	Ic = -50mA, I _B = -5mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	_	-0.9	V	Ic = -50mA, VcE = -10V
Collector-Cutoff Current	Ісво	_	_	-100	nA	V _{CB} = -320V
Collector-Cutoff Current	I _{CES}	_	_	-100	nA	V _{CE} = -320V
Emitter-Cutoff Current	ІЕВО	_	_	-100	nA	V _{EB} = -4V
Current Gain-Bandwidth Product	f⊤	50	_	_	MHz	VcE = -20V, Ic = -10mA f = 20MHz
Output Capacitance	Сово	_	-/	5	pF	V _{CB} = -20V, f = 1MHz
Switching Time	ton toff	_	95 1600	_	ns ns	I _C = -50mA, V _C = -100V I _{B1} = 5mA, I _{B2} = -10mA

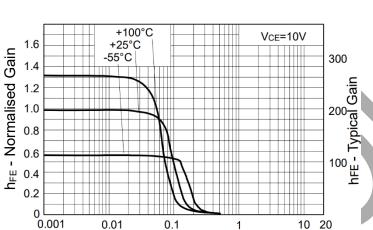
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.





Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





-lc - Collector Current (Amps) Figure. 7 h_{FE} vs. lc

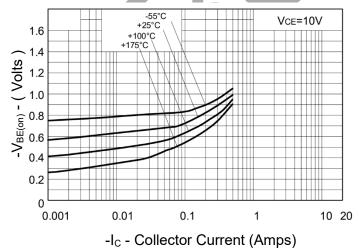
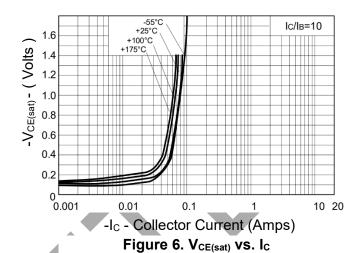
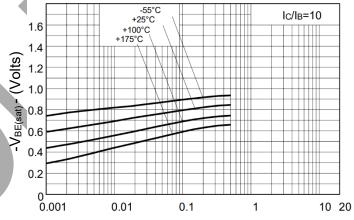


Figure 9. V_{BE(on)} vs. I_C





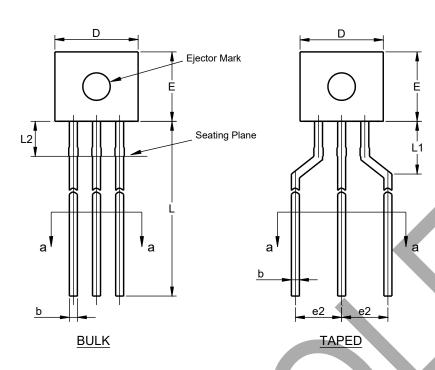
-I_C - Collector Current (Amps) Figure 8. V_{BE(sat)} vs. I_C



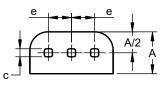
Package Outline Dimensions

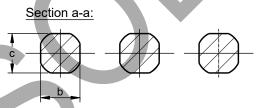
Please see http://www.diodes.com/package-outlines.html for the latest version.

E-Line



E-Line					
Dim	Min	Max	Тур		
Α	2.16	2.41	2.28		
b	0.41	0.49	0.44		
C	0.41	0.49	0.44		
D	4.37	4.77	4.57		
E	3.61	4.01	3.90		
е	1.27 REF				
e2	2.54 REF				
L	13.00	13.97	13.50		
L1	2.50	3.50			
L2	-		2.50		
All Dimensions in mm					

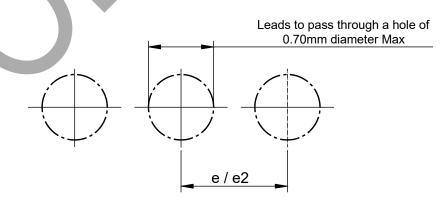




Suggested Pad Hole

Please see http://www.diodes.com/package-outlines.html for the latest version.

E-Line





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